PS2561-1, PS2561L-1, PS2561L1-1, PS2561L2-1

HIGH ISOLATION VOLTAGE SINGLE TRANSISTOR TYPE

R08DS0207EJ0200
Rev.2.00
Jun. 16, 2026

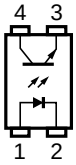
DESCRIPTION

The PS2561-1 is an optically coupled isolator containing a GaAs light emitting diode and an NPN silicon phototransistor.
The PS2561-1 is in a plastic DIP (Dual In-line Package) and the PS2561L-1 is lead bending type (Gull-wing) for surface mount.
The PS2561L1-1 is wide lead bending type.
The PS2561L2-1 is wide lead bending type for surface mount.

FEATURES

- High isolation voltage (BV = 5 000 Vr.m.s.)
- High collector to emitter voltage (V_{CEO} = 80 V)
- High current transfer ratio (CTR = 200 % TYP.)
- High-speed switching (t_r = 3 μs TYP., t_f = 5 μs TYP.)
- Ordering number of taping product: PS2561L-1-F3 : 2 000 pcs/reel
  : PS2561L2-1-F3 : 2 000 pcs/reel
- Pb-free product
- Safety standards
  - UL approved: UL 1577, Double protection
  - CSA approved: CSA C22.2 No. 62368-1, Reinforced insulation
  - BSI approved: BS EN IEC 62368-1, Reinforced insulation
  - SEMKO approved: EN IEC 62368-1, IEC 62368-1, Reinforced insulation
  - NEMKO approved: EN IEC 62368-1, Reinforced insulation
  - FIMKO approved: EN IEC 62368-1, Reinforced insulation
  - DEMKO approved: EN IEC 62368-1, Reinforced insulation
  - VDE approved: DIN EN IEC 60747-5-5 (Option)

PIN CONNECTION
(Top View)



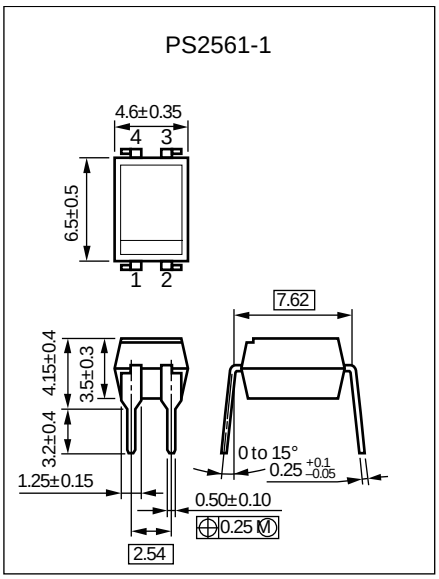
1. Anode
2. Cathode
3. Emitter
4. Collector

APPLICATIONS

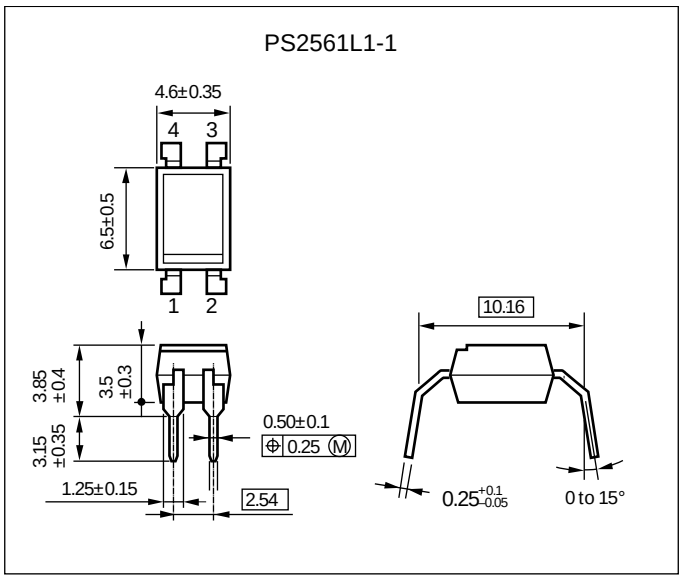
- Power supply
- Telephone/FAX.
- FA/OA equipment
- Programmable logic controllers

PACKAGE DIMENSIONS (UNIT: mm)

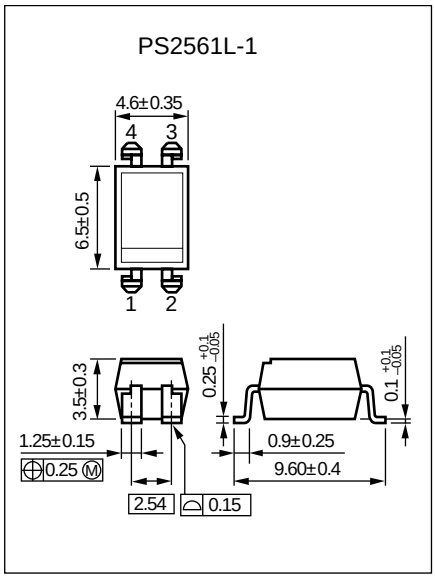
DIP Type



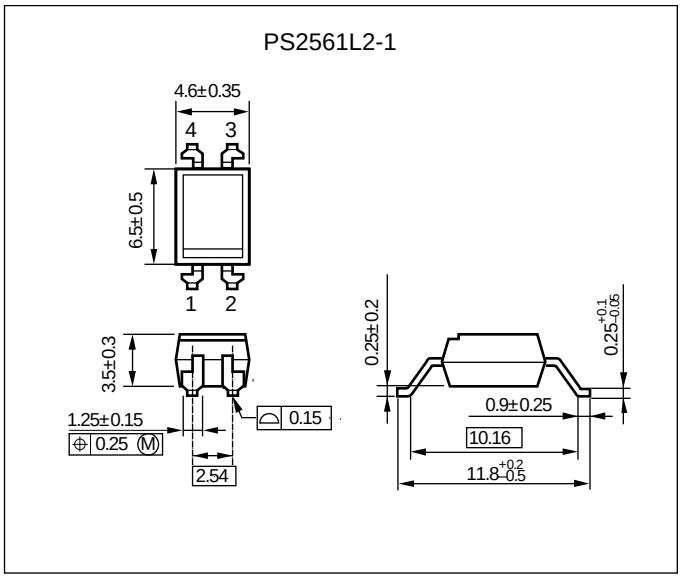
Wide Lead Bending Type



Lead Bending Type For Surface Mount



Wide Lead Bending Type For Surface Mount

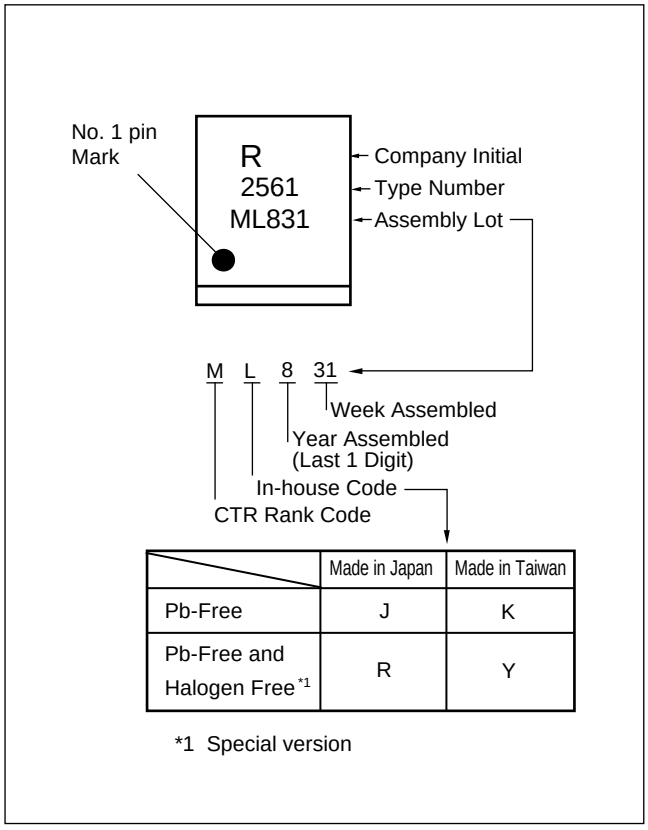


Weight (4-pin DIP) : 0.26 g (TYP.)

PHOTOCOUPLER CONSTRUCTION

Parameter	MNI.
Air Distance	7 mm
Creepage Distance	7 mm
Isolation Distance	0.4 mm

MARKING EXAMPLE



	Made in Japan	Made in Taiwan
Pb-Free	J	K
Pb-Free and Halogen Free *1	R	Y

*1 Special version

ORDERING INFORMATION

Part Number	Order Number *1	Solder Plating Specification	Packing Style	Safety Standard Approval	Application Part Number *2
PS2561-1	PS2561-1-A	Pb-Free	Magazine case 100 pcs	Standard products (UL, CSA, BSI, NEMKO, SEMKO, DEMKO, FIMKO Approved)	PS2561-1
PS2561L-1	PS2561L-1-A				PS2561L-1
PS2561L1-1	PS2561L1-1-A				PS2561L1-1
PS2561L2-1	PS2561L2-1-A				PS2561L2-1
PS2561L-1-F3	PS2561L-1-F3-A		Embossed Tape 2 000 pcs/reel		PS2561L-1
PS2561L2-1-F3	PS2561L2-1-F3-A				PS2561L2-1
PS2561-1-V	PS2561-1-V-A		Magazine case 100 pcs	UL, CSA, BSI, SEMKO, NEMKO, FIMKO, DEMKO, VDE Approved	PS2561-1
PS2561L-1-V	PS2561L-1-V-A				PS2561L-1
PS2561L1-1-V	PS2561L1-1-V-A				PS2561L1-1
PS2561L2-1-V	PS2561L2-1-V-A				PS2561L2-1
PS2561L-1-V-F3	PS2561L-1-V-F3-A		Embossed Tape 2 000 pcs/reel		PS2561L-1
PS2561L2-1-V-F3	PS2561L2-1-V-F3-A				PS2561L2-1
PS2561-1	PS2561-1Y-A	Special version (Pb-Free and Halogen Free)	Magazine case 100 pcs	Standard products (UL, CSA, BSI, NEMKO, SEMKO, DEMKO, FIMKO Approved)	PS2561-1
PS2561L-1	PS2561L-1Y-A				PS2561L-1
PS2561L1-1	PS2561L1-1Y-A				PS2561L1-1
PS2561L2-1	PS2561L2-1Y-A				PS2561L2-1
PS2561L-1-F3	PS2561L-1Y-F3-A		Embossed Tape 2 000 pcs/reel		PS2561L-1
PS2561L2-1-F3	PS2561L2-1Y-F3-A				PS2561L2-1
PS2561-1-V	PS2561-1Y-V-A		Magazine case 100 pcs	UL, CSA, BSI, SEMKO, NEMKO, FIMKO, DEMKO, VDE Approved	PS2561-1
PS2561L-1-V	PS2561L-1Y-V-A				PS2561L-1
PS2561L1-1-V	PS2561L1-1Y-V-A				PS2561L1-1
PS2561L2-1-V	PS2561L2-1Y-V-A				PS2561L2-1
PS2561L-1-V-F3	PS2561L-1Y-V-F3-A		Embossed Tape 2 000 pcs/reel		PS2561L-1
PS2561L2-1-V-F3	PS2561L2-1Y-V-F3-A				PS2561L2-1

Notes: *1. When specifying CTR rank, please add “-CTR rank” after Order Number.

ex. L rank : PS2561-1-A-L

Notes: *2. For the application of the safety standard, the following part number should be used.

ABSOLUTE MAXIMUM RATINGS (T_A = 25 °C, unless otherwise specified)

Parameter		Symbol	Ratings	Unit
Diode	Reverse Voltage	V_R	6	V
	Forward Current (DC)	I_F	80	mA
	Power Dissipation Derating	ΔP_D/°C	1.5	mW/°C
	Power Dissipation	P_D	150	mW
	Peak Forward Current *1	I_{FP}	1	A
Transistor	Collector to Emitter Voltage	V_{CEO}	80	V
	Emitter to Collector Voltage	V_{ECO}	7	V
	Collector Current	I_C	50	mA
	Power Dissipation Derating	ΔP_C/°C	1.5	mW/°C
	Power Dissipation	P_C	150	mW
Isolation Voltage *2		BV	5 000	Vr.m.s.
Operating Ambient Temperature		T_A	–55 to +100	°C
Storage Temperature		T_{stg}	–55 to +150	°C

Note: *1. PW = 100 µs, Duty Cycle = 1 %

*2. AC voltage for 1 minute at T_A = 25 °C, RH = 60 % between input and output.
Pins 1-2 shorted together, 3-4 shorted together.

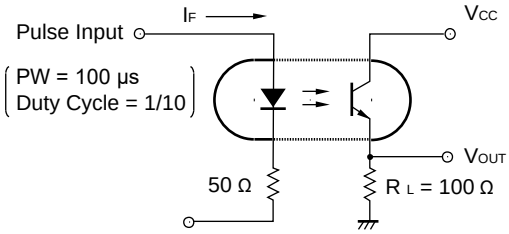
ELECTRICAL CHARACTERISTICS (T_A = 25 °C)

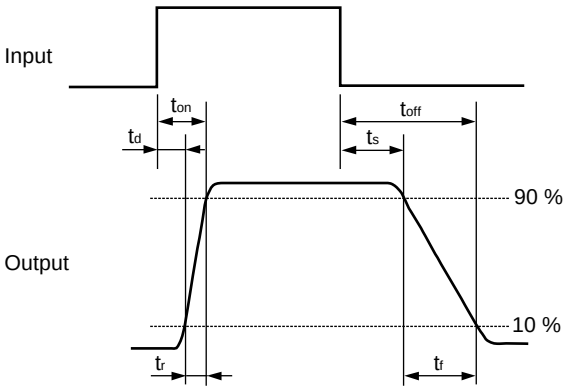
Parameter		Symbol	Conditions	MIN.	TYP.	MAX.	Unit
Diode	Forward Voltage	V_F	I_F = 10 mA		1.17	1.4	V
	Reverse Current	I_R	V_R = 5 V			5	μA
	Terminal Capacitance	C_t	V = 0 V, f = 1.0 MHz		50		pF
Transistor	Collector to Emitter Dark Current	I_{CEO}	V_{CE} = 80 V, I_F = 0 mA			100	nA
Coupled	Current Transfer Ratio (I_C/I_F) *1	CTR	I_F = 5 mA, V_{CE} = 5 V	80	200	400	%
	Collector Saturation Voltage	$V_{CE (sat)}$	I_F = 10 mA, I_C = 2 mA			0.3	V
	Isolation Resistance	R_{I-O}	V_{I-O} = 1.0 kV$_{DC}$	10^{11}			Ω
	Isolation Capacitance	C_{I-O}	V = 0 V, f = 1.0 MHz		0.5		pF
	Rise Time *2	t_r	V_{CC} = 10 V, I_C = 2 mA, R_L = 100 Ω		3		μs
	Fall Time *2	t_f			5		

Note: *1. CTR rank

L : 200 to 400 (%)
M : 80 to 240 (%)
D : 100 to 300 (%)
H : 80 to 160 (%)
W : 130 to 260 (%)

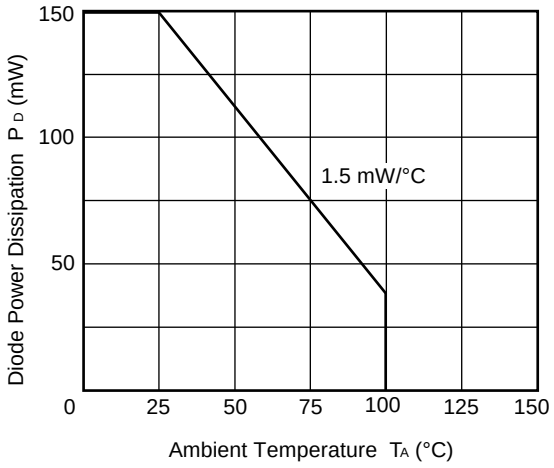
*2. Test Circuit for Switching Time



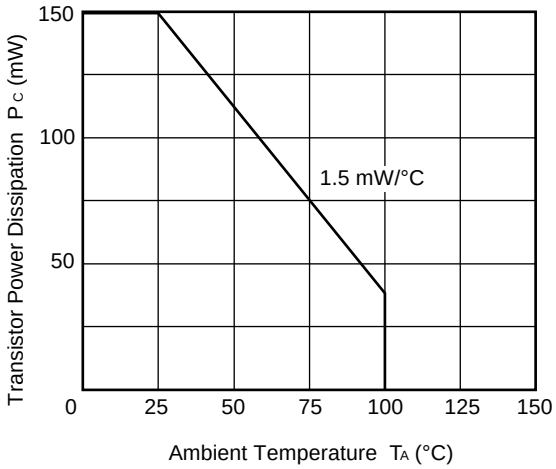


TYPICAL CHARACTERISTICS (T_A = 25 °C, unless otherwise specified)

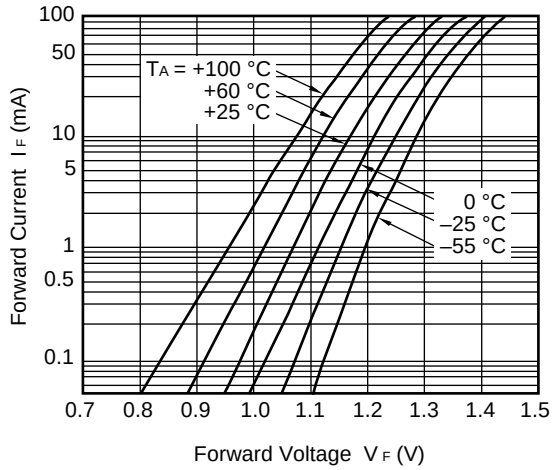
DIODE POWER DISSIPATION vs. AMBIENT TEMPERATURE



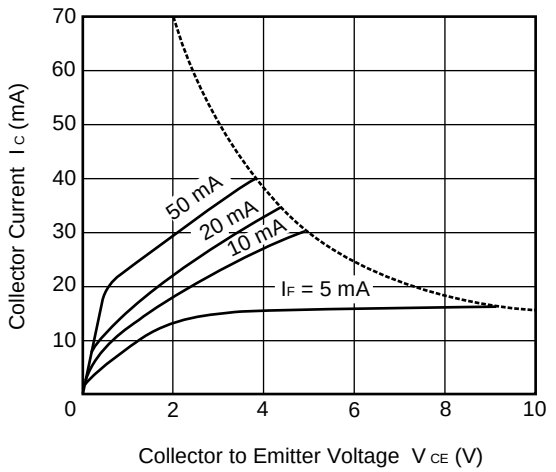
TRANSISTOR POWER DISSIPATION vs. AMBIENT TEMPERATURE



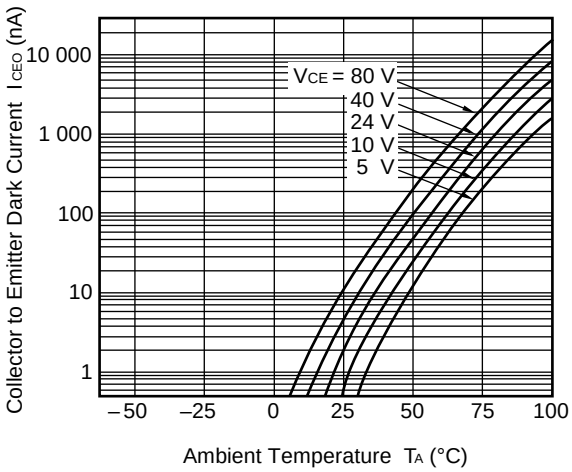
FORWARD CURRENT vs. FORWARD VOLTAGE



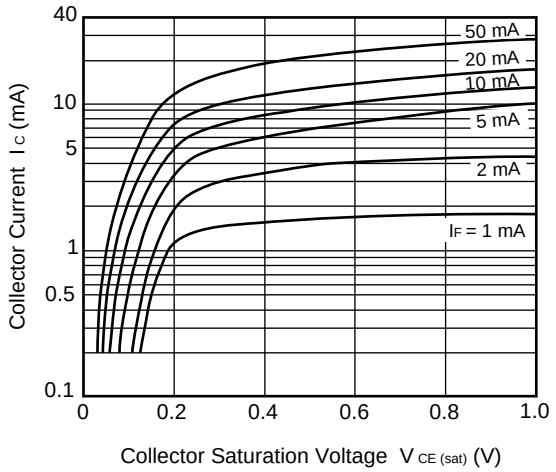
COLLECTOR CURRENT vs. COLLECTOR TO EMITTER VOLTAGE



COLLECTOR TO EMITTER DARK CURRENT vs. AMBIENT TEMPERATURE

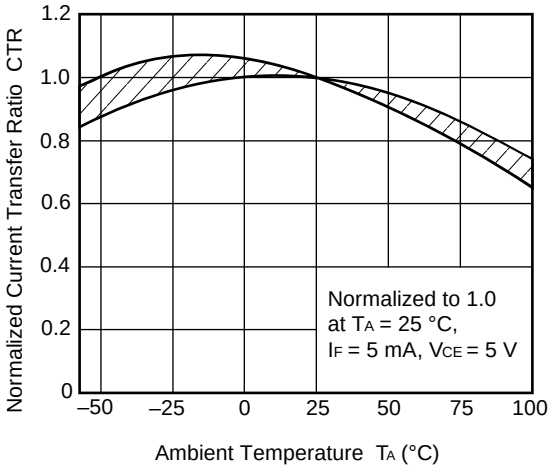


COLLECTOR CURRENT vs. COLLECTOR SATURATION VOLTAGE

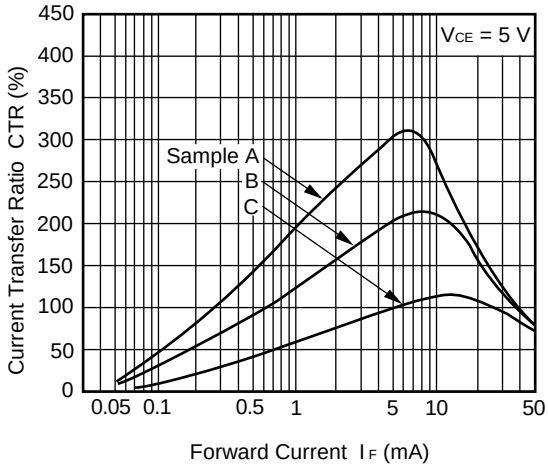


Remark The graphs indicate nominal characteristics.

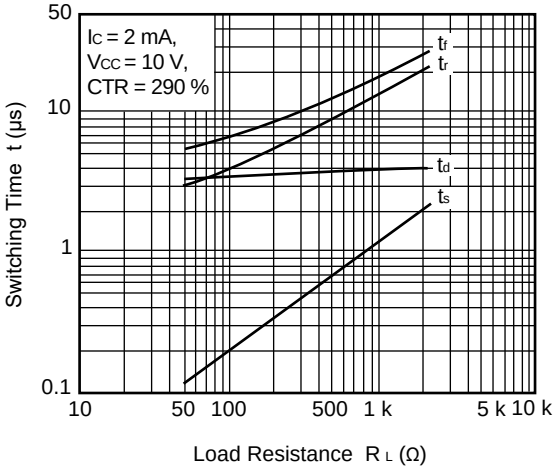
NORMALIZED CURRENT TRANSFER RATIO vs. AMBIENT TEMPERATURE



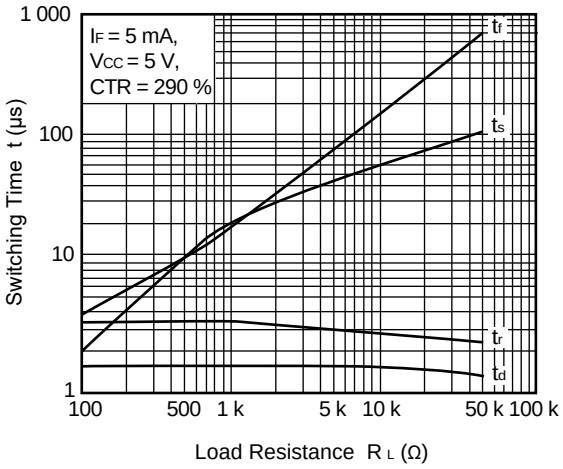
CURRENT TRANSFER RATIO vs. FORWARD CURRENT



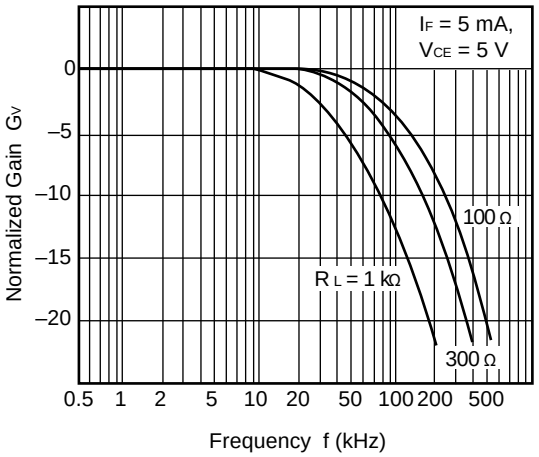
SWITCHING TIME vs. LOAD RESISTANCE



SWITCHING TIME vs. LOAD RESISTANCE



FREQUENCY RESPONSE

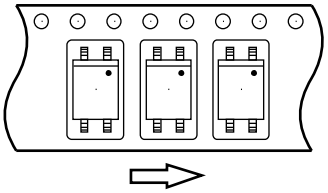


Remark The graphs indicate nominal characteristics.

TAPING SPECIFICATIONS (UNIT: mm)

Tape Direction

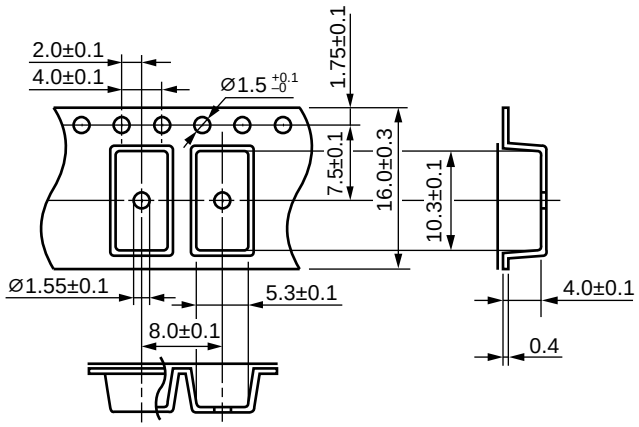
PS2561L-1-F3



Direction of feed

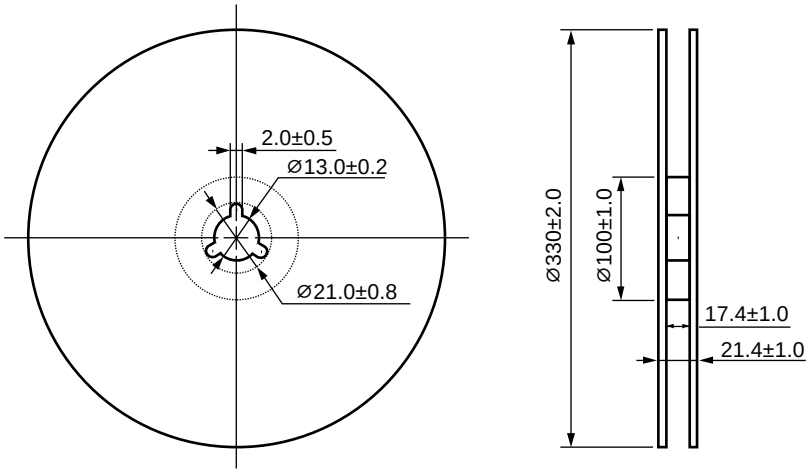
Outline and Dimensions (Tape)

Unit : mm



Outline and Dimensions (Reel)

Unit : mm

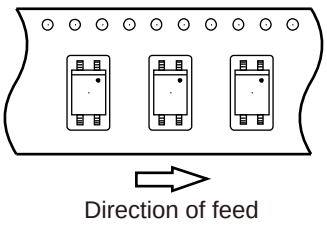


Packing: 2 000 pcs/reel

TAPING SPECIFICATIONS (UNIT: mm)

Tape Direction

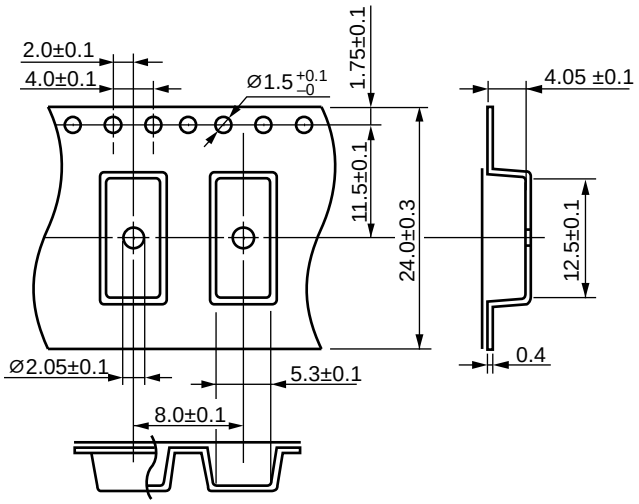
PS2561L2-1-F3



Direction of feed

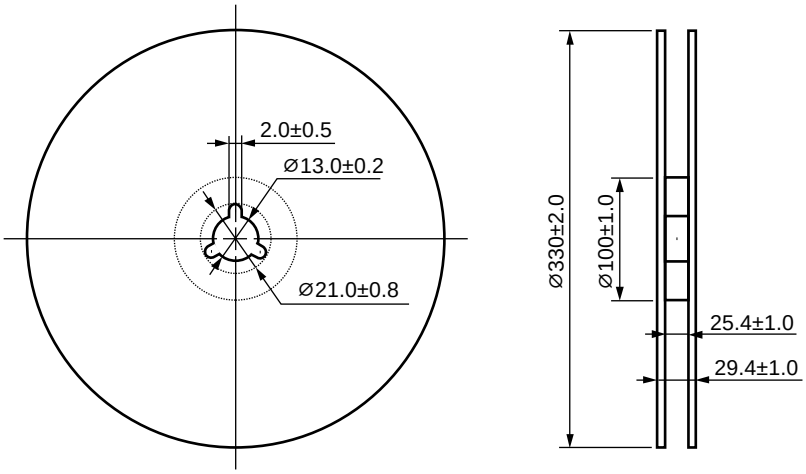
Outline and Dimensions (Tape)

(Unit : mm)



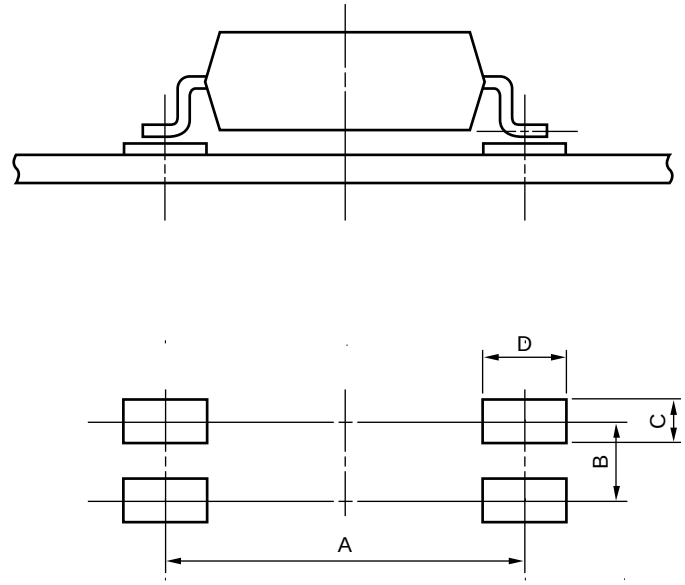
Outline and Dimensions (Reel)

(Unit : mm)



Packing: 2 000 pcs/reel

RECOMMENDED MOUNT PAD DIMENSIONS (UNIT: mm)



Part Number	Lead Bending	A	B	C	D
PS2561L	Lead Bending Type For Surface Mount	8.2	2.54	1.7	2.2
PS2561L2	Wide Lead Bending Type For Surface Mount	10.2	2.54	1.7	2.2

Remark All dimensions in this figure must be evaluated before use.

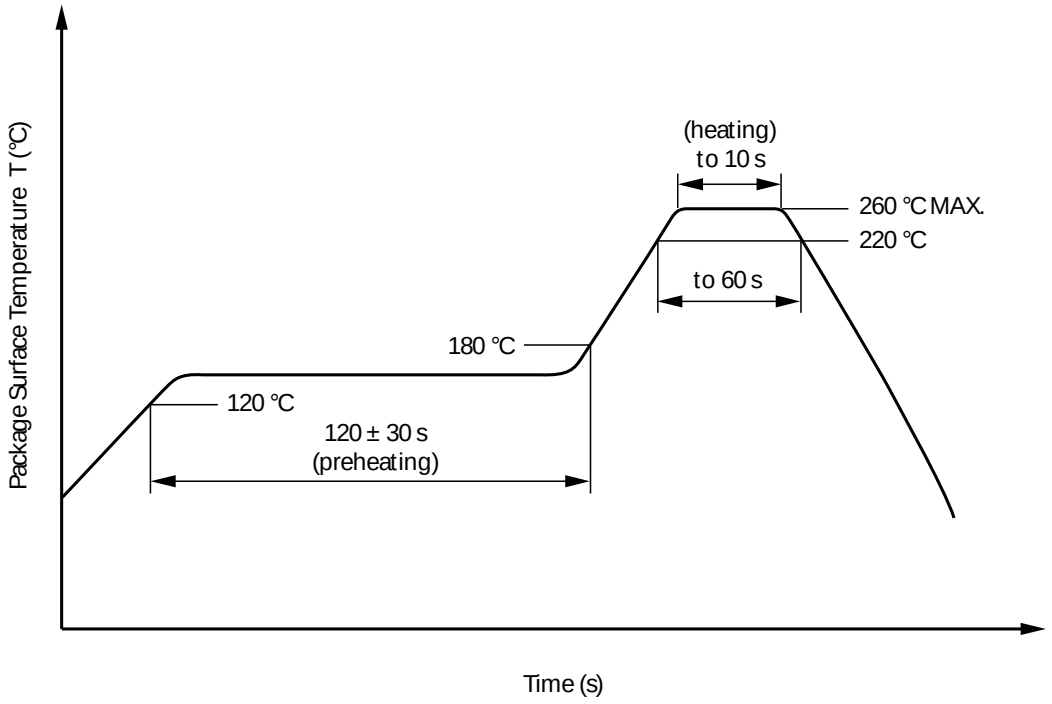
NOTES ON HANDLING

1. Recommended soldering conditions

(1) Infrared reflow soldering

• Peak reflow temperature	260 °C or below (package surface temperature)
• Time of peak reflow temperature	10 s or less
• Time of temperature higher than 220 °C	60 s or less
• Time to preheat temperature from 120 to 180 °C	120 ± 30 s
• Number of reflows	Three
• Flux	Rosin flux containing small amount of chlorine (The flux with a maximum chlorine content of 0.2 Wt% is recommended.)

Recommended Temperature Profile of Infrared Reflow



(2) Wave soldering

• Temperature	260 °C or below (molten solder temperature)
• Time	10 s or less
• Preheating conditions	120 °C or below (package surface temperature)
• Number of times	One (Allowed to be dipped in solder including plastic mold portion.)
• Flux	Rosin flux containing small amount of chlorine (The flux with a maximum chlorine content of 0.2 Wt% is recommended.)

(3) Soldering by Soldering Iron

• Peak temperature (lead part temperature)	350 °C or below
• Time (per one side)	3 s or less
• Flux	Rosin flux containing small amount of chlorine (The flux with a maximum chlorine content of 0.2 Wt% is recommended.)
•Place	1.5 to 2.0 mm or more away from the root of the lead

(4) Cautions

• Flux cleaning	Avoid cleaning with Freon- or halogen-based (chlorinated etc.) solvents.
• Fixing/Coating	Do not use fixing agents or coatings containing halogen-based substances.

2. Cautions regarding noise
   Be aware that when voltage is applied suddenly between the photocoupler's input and output or between collector-emitters at startup, the output transistor may enter the on state, even if the voltage is within the absolute maximum ratings.

3. Measurement conditions of current transfer ratios (CTR), which differ according to photocoupler
   Check the setting values before use, since the forward current conditions at CTR measurement differ according to product.
   When using products other than at the specified forward current, the characteristics curves may differ from the standard curves due to CTR value variations or the like. This tendency may sometimes be obvious, especially below I_F = 1 mA.
   Therefore, check the characteristics under the actual operating conditions and thoroughly take variations or the like into consideration before use.

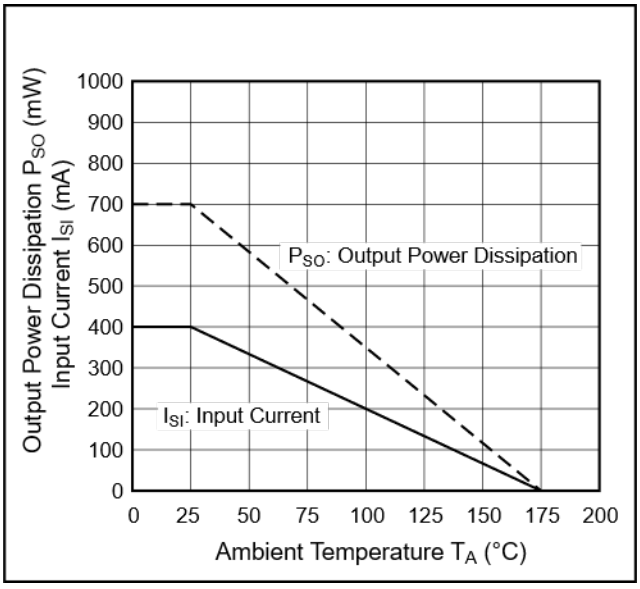
USAGE CAUTIONS

1. Protect against static electricity when handling.
2. Avoid storage at a high temperature and high humidity.
3. Avoid cleaning with Freon based or halogen-based (chlorinated etc.) solvents.
4. Do not use fixing agents or coatings containing halogen-based substances.

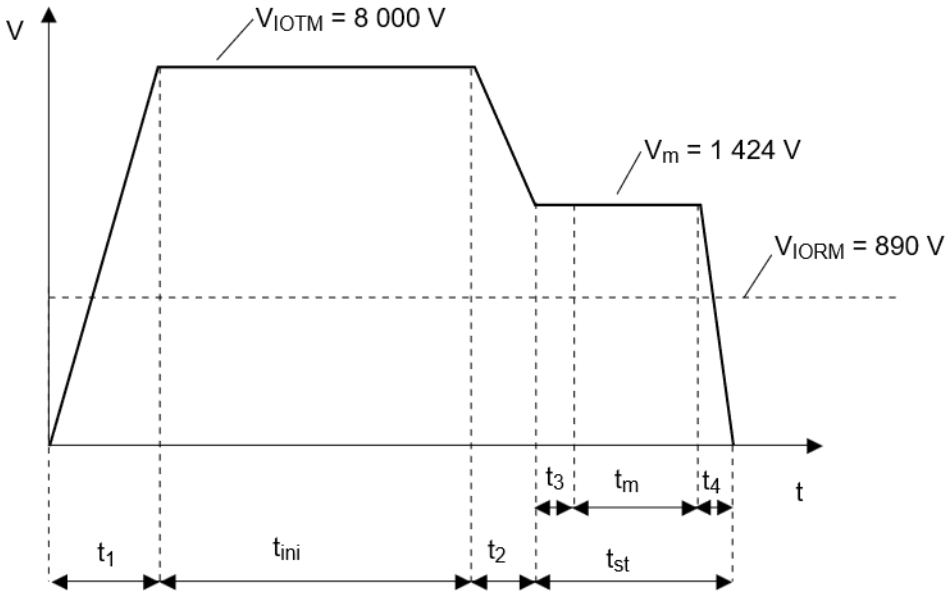
SPECIFICATION OF VDE MARKS LICENSE DOCUMENT

Parameter	Symbol	Rating	Unit
Climatic test class (IEC 60068-1/DIN EN 60068-1)		55/100/21	
Dielectric strength maximum operating isolation voltage Test voltage (partial discharge test, procedure a for type test and random test) $V_m = 1.6 \times V_{IORM.}$, $q_{pd} < 5$ pC	 V_{IORM} V_m	 890 1 424	 V_{peak} V_{peak}
Test voltage (partial discharge test, procedure b for all devices) $V_m = 1.875 \times V_{IORM.}$, $q_{pd} < 5$ pC	V_m	1 669	V_{peak}
Highest permissible overvoltage	V_{IOTM}	8 000	V_{peak}
Degree of pollution (IEC 60664-1/DIN EN 60664-1 (VDE 0110-1))		2	
Comparative tracking index (IEC 60112/DIN EN 60112 (VDE 0303-11))	CTI	175	
Material group (IEC 60664-1/DIN EN 60664-1 (VDE 0110-1))		III a	
Storage temperature range	T_{stg}	−55 to +150	°C
Operating temperature range	T_A	−55 to +100	°C
Isolation resistance, minimum value V_{I-O} = 500 V dc, T_A = 25 °C V_{I-O} = 500 V dc, T_A = maximum temperature of rating, at least 100 °C	 R_{I-O} MIN. R_{I-O} MIN.	 10^{12} 10^{11}	 Ω Ω
Safety maximum ratings (maximum permissible in case of fault, see thermal derating curve) Maximum ambient temperature Maximum input current Maximum output power dissipation Isolation resistance, minimum value at V_{I-O} = 500 V dc, $T_A = T_S$	 T_S I_{SI} P_{SO} R_{I-O} MIN.	 175 400 700 10^9	 °C mA mW Ω

Dependence of maximum safety ratings on ambient temperature

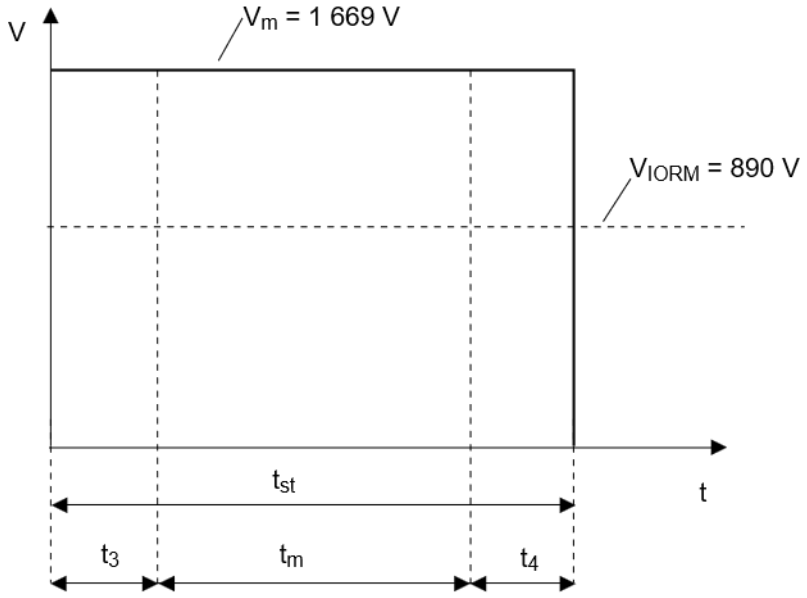


Method a) Destructive Test, Type and Sample Test



t_1, t_2 = 1 to 10 sec
t_3, t_4 = 1 sec
t_m = 10 sec
t_{st} = 12 sec
t_{ini} = 60 sec

Method b) Non-destructive Test, 100% Production Test



t_3, t_4 = 0.1 sec
t_m = 1.0 sec
t_{st} = 1.2 sec

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